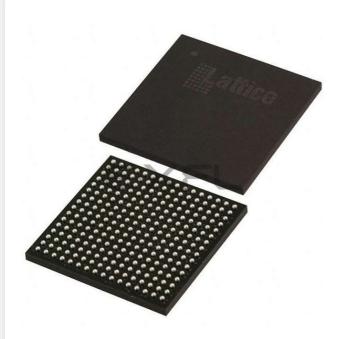
E · Clattice Semiconductor Corporation - <u>LCMXO2-4000HC-5FTG256C Datasheet</u>



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	540
Number of Logic Elements/Cells	4320
Total RAM Bits	94208
Number of I/O	206
Number of Gates	-
Voltage - Supply	2.375V ~ 3.465V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-FTBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo2-4000hc-5ftg256c

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Introduction

The MachXO2 family of ultra low power, instant-on, non-volatile PLDs has six devices with densities ranging from 256 to 6864 Look-Up Tables (LUTs). In addition to LUT-based, low-cost programmable logic these devices feature Embedded Block RAM (EBR), Distributed RAM, User Flash Memory (UFM), Phase Locked Loops (PLLs), preengineered source synchronous I/O support, advanced configuration support including dual-boot capability and hardened versions of commonly used functions such as SPI controller, I²C controller and timer/counter. These features allow these devices to be used in low cost, high volume consumer and system applications.

The MachXO2 devices are designed on a 65 nm non-volatile low power process. The device architecture has several features such as programmable low swing differential I/Os and the ability to turn off I/O banks, on-chip PLLs and oscillators dynamically. These features help manage static and dynamic power consumption resulting in low static power for all members of the family.

The MachXO2 devices are available in two versions – ultra low power (ZE) and high performance (HC and HE) devices. The ultra low power devices are offered in three speed grades –1, –2 and –3, with –3 being the fastest. Similarly, the high-performance devices are offered in three speed grades: –4, –5 and –6, with –6 being the fastest. HC devices have an internal linear voltage regulator which supports external V_{CC} supply voltages of 3.3 V or 2.5 V. ZE and HE devices only accept 1.2 V as the external V_{CC} supply voltage. With the exception of power supply voltage all three types of devices (ZE, HC and HE) are functionally compatible and pin compatible with each other.

The MachXO2 PLDs are available in a broad range of advanced halogen-free packages ranging from the space saving 2.5 mm x 2.5 mm WLCSP to the 23 mm x 23 mm fpBGA. MachXO2 devices support density migration within the same package. Table 1-1 shows the LUT densities, package and I/O options, along with other key parameters.

The pre-engineered source synchronous logic implemented in the MachXO2 device family supports a broad range of interface standards, including LPDDR, DDR, DDR2 and 7:1 gearing for display I/Os.

The MachXO2 devices offer enhanced I/O features such as drive strength control, slew rate control, PCI compatibility, bus-keeper latches, pull-up resistors, pull-down resistors, open drain outputs and hot socketing. Pull-up, pull-down and bus-keeper features are controllable on a "per-pin" basis.

A user-programmable internal oscillator is included in MachXO2 devices. The clock output from this oscillator may be divided by the timer/counter for use as clock input in functions such as LED control, key-board scanner and similar state machines.

The MachXO2 devices also provide flexible, reliable and secure configuration from on-chip Flash memory. These devices can also configure themselves from external SPI Flash or be configured by an external master through the JTAG test access port or through the I²C port. Additionally, MachXO2 devices support dual-boot capability (using external Flash memory) and remote field upgrade (TransFR) capability.

Lattice provides a variety of design tools that allow complex designs to be efficiently implemented using the MachXO2 family of devices. Popular logic synthesis tools provide synthesis library support for MachXO2. Lattice design tools use the synthesis tool output along with the user-specified preferences and constraints to place and route the design in the MachXO2 device. These tools extract the timing from the routing and back-annotate it into the design for timing verification.

Lattice provides many pre-engineered IP (Intellectual Property) LatticeCORE[™] modules, including a number of reference designs licensed free of charge, optimized for the MachXO2 PLD family. By using these configurable soft core IP cores as standardized blocks, users are free to concentrate on the unique aspects of their design, increasing their productivity.



MachXO2 Family Data Sheet Architecture

March 2016

Data Sheet DS1035

Architecture Overview

The MachXO2 family architecture contains an array of logic blocks surrounded by Programmable I/O (PIO). The larger logic density devices in this family have sysCLOCK[™] PLLs and blocks of sysMEM Embedded Block RAM (EBRs). Figure 2-1 and Figure 2-2 show the block diagrams of the various family members.





Note: MachXO2-256, and MachXO2-640/U are similar to MachXO2-1200. MachXO2-256 has a lower LUT count and no PLL or EBR blocks. MachXO2-640 has no PLL, a lower LUT count and two EBR blocks. MachXO2-640U has a lower LUT count, one PLL and seven EBR blocks.

Figure 2-2. Top View of the MachXO2-4000 Device



Note: MachXO2-1200U, MachXO2-2000/U and MachXO2-7000 are similar to MachXO2-4000. MachXO2-1200U and MachXO2-2000 have a lower LUT count, one PLL, and eight EBR blocks. MachXO2-2000U has a lower LUT count, two PLLs, and 10 EBR blocks. MachXO2-7000 has a higher LUT count, two PLLs, and 26 EBR blocks.

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The logic blocks, Programmable Functional Unit (PFU) and sysMEM EBR blocks, are arranged in a two-dimensional grid with rows and columns. Each row has either the logic blocks or the EBR blocks. The PIO cells are located at the periphery of the device, arranged in banks. The PFU contains the building blocks for logic, arithmetic, RAM, ROM, and register functions. The PIOs utilize a flexible I/O buffer referred to as a sysIO buffer that supports operation with a variety of interface standards. The blocks are connected with many vertical and horizontal routing channel resources. The place and route software tool automatically allocates these routing resources.

In the MachXO2 family, the number of sysIO banks varies by device. There are different types of I/O buffers on the different banks. Refer to the details in later sections of this document. The sysMEM EBRs are large, dedicated fast memory blocks; these blocks are found in MachXO2-640/U and larger devices. These blocks can be configured as RAM, ROM or FIFO. FIFO support includes dedicated FIFO pointer and flag "hard" control logic to minimize LUT usage.

The MachXO2 registers in PFU and sysl/O can be configured to be SET or RESET. After power up and device is configured, the device enters into user mode with these registers SET/RESET according to the configuration setting, allowing device entering to a known state for predictable system function.

The MachXO2 architecture also provides up to two sysCLOCK Phase Locked Loop (PLL) blocks on MachXO2-640U, MachXO2-1200/U and larger devices. These blocks are located at the ends of the on-chip Flash block. The PLLs have multiply, divide, and phase shifting capabilities that are used to manage the frequency and phase relationships of the clocks.

MachXO2 devices provide commonly used hardened functions such as SPI controller, I²C controller and timer/ counter. MachXO2-640/U and higher density devices also provide User Flash Memory (UFM). These hardened functions and the UFM interface to the core logic and routing through a WISHBONE interface. The UFM can also be accessed through the SPI, I²C and JTAG ports.

Every device in the family has a JTAG port that supports programming and configuration of the device as well as access to the user logic. The MachXO2 devices are available for operation from 3.3 V, 2.5 V and 1.2 V power supplies, providing easy integration into the overall system.

PFU Blocks

The core of the MachXO2 device consists of PFU blocks, which can be programmed to perform logic, arithmetic, distributed RAM and distributed ROM functions. Each PFU block consists of four interconnected slices numbered 0 to 3 as shown in Figure 2-3. Each slice contains two LUTs and two registers. There are 53 inputs and 25 outputs associated with each PFU block.



Figure 2-5. Primary Clocks for MachXO2 Devices



Primary clocks for MachXO2-640U, MachXO2-1200/U and larger devices.

Note: MachXO2-640 and smaller devices do not have inputs from the Edge Clock Divider or PLL and fewer routing inputs. These devices have 17:1 muxes instead of 27:1 muxes.

Eight secondary high fanout nets are generated from eight 8:1 muxes as shown in Figure 2-6. One of the eight inputs to the secondary high fanout net input mux comes from dual function clock pins and the remaining seven come from internal routing. The maximum frequency for the secondary clock network is shown in MachXO2 External Switching Characteristics table.



This phase shift can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after a phase adjustment on the output used as the feedback source and not relock until the $t_{I,OCK}$ parameter has been satisfied.

The MachXO2 also has a feature that allows the user to select between two different reference clock sources dynamically. This feature is implemented using the PLLREFCS primitive. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

The MachXO2 PLL contains a WISHBONE port feature that allows the PLL settings, including divider values, to be dynamically changed from the user logic. When using this feature the EFB block must also be instantiated in the design to allow access to the WISHBONE ports. Similar to the dynamic phase adjustment, when PLL settings are updated through the WISHBONE port the PLL may lose lock and not relock until the t_{LOCK} parameter has been satisfied. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

For more details on the PLL and the WISHBONE interface, see TN1199, MachXO2 sysCLOCK PLL Design and Usage Guide.



Figure 2-7. PLL Diagram

Table 2-4 provides signal descriptions of the PLL block.

Table 2-4. PLL Signal	Descriptions
-----------------------	--------------

Port Name	I/O	Description
CLKI	I	Input clock to PLL
CLKFB	I	Feedback clock
PHASESEL[1:0]	I	Select which output is affected by Dynamic Phase adjustment ports
PHASEDIR	I	Dynamic Phase adjustment direction
PHASESTEP	I	Dynamic Phase step – toggle shifts VCO phase adjust by one step.



 Table 2-5. sysMEM Block Configurations

Memory Mode	Configurations
Single Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9
True Dual Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9
Pseudo Dual Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9 512 x 18
FIFO	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9 512 x 18

Bus Size Matching

All of the multi-port memory modes support different widths on each of the ports. The RAM bits are mapped LSB word 0 to MSB word 0, LSB word 1 to MSB word 1, and so on. Although the word size and number of words for each port varies, this mapping scheme applies to each port.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration. EBR initialization data can be loaded from the UFM. To maximize the number of UFM bits, initialize the EBRs used in your design to an all-zero pattern. Initializing to an all-zero pattern does not use up UFM bits. MachXO2 devices have been designed such that multiple EBRs share the same initialization memory space if they are initialized to the same pattern.

By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

Memory Cascading

Larger and deeper blocks of RAM can be created using EBR sysMEM Blocks. Typically, the Lattice design tools cascade memory transparently, based on specific design inputs.

Single, Dual, Pseudo-Dual Port and FIFO Modes

Figure 2-8 shows the five basic memory configurations and their input/output names. In all the sysMEM RAM modes, the input data and addresses for the ports are registered at the input of the memory array. The output data of the memory is optionally registered at the memory array output.



Output Register Block

The output register block registers signals from the core of the device before they are passed to the sysIO buffers.

Left, Top, Bottom Edges

In SDR mode, D0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type register or latch.

In DDR generic mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the same clock is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-14 shows the output register block on the left, top and bottom edges.

Figure 2-14. MachXO2 Output Register Block Diagram (PIO on the Left, Top and Bottom Edges)



Right Edge

The output register block on the right edge is a superset of the output register on left, top and bottom edges of the device. In addition to supporting SDR and Generic DDR modes, the output register blocks for PIOs on the right edge include additional logic to support DDR-memory interfaces. Operation of this block is similar to that of the output register block on other edges.

In DDR memory mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the DQSW90 signal is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-15 shows the output register block on the right edge.



Configuration and Testing

This section describes the configuration and testing features of the MachXO2 family.

IEEE 1149.1-Compliant Boundary Scan Testability

All MachXO2 devices have boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: TDI, TDO, TCK and TMS. The test access port shares its power supply with V_{CCIO} Bank 0 and can operate with LVCMOS3.3, 2.5, 1.8, 1.5, and 1.2 standards.

For more details on boundary scan test, see AN8066, Boundary Scan Testability with Lattice sysIO Capability and TN1087, Minimizing System Interruption During Configuration Using TransFR Technology.

Device Configuration

All MachXO2 devices contain two ports that can be used for device configuration. The Test Access Port (TAP), which supports bit-wide configuration and the sysCONFIG port which supports serial configuration through I²C or SPI. The TAP supports both the IEEE Standard 1149.1 Boundary Scan specification and the IEEE Standard 1532 In-System Configuration specification. There are various ways to configure a MachXO2 device:

- 1. Internal Flash Download
- 2. JTAG
- 3. Standard Serial Peripheral Interface (Master SPI mode) interface to boot PROM memory
- 4. System microprocessor to drive a serial slave SPI port (SSPI mode)
- 5. Standard I²C Interface to system microprocessor

Upon power-up, the configuration SRAM is ready to be configured using the selected sysCONFIG port. Once a configuration port is selected, it will remain active throughout that configuration cycle. The IEEE 1149.1 port can be activated any time after power-up by sending the appropriate command through the TAP port. Optionally the device can run a CRC check upon entering the user mode. This will ensure that the device was configured correctly.

The sysCONFIG port has 10 dual-function pins which can be used as general purpose I/Os if they are not required for configuration. See TN1204, MachXO2 Programming and Configuration Usage Guide for more information about using the dual-use pins as general purpose I/Os.

Lattice design software uses proprietary compression technology to compress bit-streams for use in MachXO2 devices. Use of this technology allows Lattice to provide a lower cost solution. In the unlikely event that this technology is unable to compress bitstreams to fit into the amount of on-chip Flash memory, there are a variety of techniques that can be utilized to allow the bitstream to fit in the on-chip Flash memory. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

The Test Access Port (TAP) has five dual purpose pins (TDI, TDO, TMS, TCK and JTAGENB). These pins are dual function pins - TDI, TDO, TMS and TCK can be used as general purpose I/O if desired. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

TransFR (Transparent Field Reconfiguration)

TransFR is a unique Lattice technology that allows users to update their logic in the field without interrupting system operation using a simple push-button solution. For more details refer to TN1087, Minimizing System Interruption During Configuration Using TransFR Technology for details.



sysIO Single-Ended DC Electrical Characteristics^{1, 2}

Input/Output	V	/ _{IL}	V _I	н	V _{OL} Max.	V _{OH} Min.	l _{OL} Max.⁴	I _{OH} Max.⁴
Standard	Min. (V) ³	Max. (V)	Min. (V)	Max. (V)	(V)	(V)	(mA)	(mA)
							4	-4
							8	-8
LVCMOS 3.3	-0.3	0.8	2.0	3.6	0.4	$V_{CCIO} - 0.4$	12	-12
LVTTL	0.0	0.0	2.0	0.0			16	-16
							24	-24
					0.2	V _{CCIO} – 0.2	0.1	-0.1
							4	-4
					0.4	V _{CCIO} – 0.4	8	-8
LVCMOS 2.5	-0.3	0.7	1.7	3.6	0.4	VCCIO 0.4	12	-12
							16	-16
					0.2	V _{CCIO} – 0.2	0.1	-0.1
							4	-4
LVCMOS 1.8	-0.3	0.35V _{CCIO}	0.65V _{CCIO}	3.6	0.4	$V_{CCIO} - 0.4$	8	-8
	-0.5	0.33 v CCIO	0.03 v CCIO	5.0			12	-12
					0.2	V _{CCIO} – 0.2	0.1	-0.1
					0.4	V _{CCIO} – 0.4	4	-4
LVCMOS 1.5	-0.3	0.35V _{CCIO}	0.65V _{CCIO}	3.6	0.4	ACCIO - 014	8	-8
					0.2	V _{CCIO} – 0.2	0.1	-0.1
	-0.3				0.4	V _{CCIO} – 0.4	4	-2
LVCMOS 1.2		0.35V _{CCIO}	0.65V _{CCIO}	3.6	0.4	VCCIO 0.4	8	-6
					0.2	V _{CCIO} – 0.2	0.1	-0.1
PCI	-0.3	0.3V _{CCIO}	0.5V _{CCIO}	3.6	0.1V _{CCIO}	0.9V _{CCIO}	1.5	-0.5
SSTL25 Class I	-0.3	V _{REF} - 0.18	V _{REF} + 0.18	3.6	0.54	V _{CCIO} - 0.62	8	8
SSTL25 Class II	-0.3	V _{REF} - 0.18	V _{REF} + 0.18	3.6	NA	NA	NA	NA
SSTL18 Class I	-0.3	V _{REF} – 0.125	V _{REF} + 0.125	3.6	0.40	V _{CCIO} - 0.40	8	8
SSTL18 Class II	-0.3	V _{REF} – 0.125	V _{REF} + 0.125	3.6	NA	NA	NA	NA
HSTL18 Class I	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	0.40	V _{CCIO} - 0.40	8	8
HSTL18 Class II	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS25R33	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS18R33	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS18R25	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS15R33	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS15R25	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	NA	NA	NA	NA
LVCMOS12R33	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	0.40	NA Open Drain	24, 16, 12, 8, 4	NA Open Drain
LVCMOS12R25	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	0.40	NA Open Drain	16, 12, 8, 4	NA Open Drain
LVCMOS10R33	-0.3	V _{REF} – 0.1	V _{REF} + 0.1	3.6	0.40	NA Open Drain	24, 16, 12, 8, 4	NA Open Drain



LVPECL

The MachXO2 family supports the differential LVPECL standard through emulation. This output standard is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all the devices. The LVPECL input standard is supported by the LVDS differential input buffer. The scheme shown in Differential LVPECL is one possible solution for point-to-point signals.

Figure 3-3. Differential LVPECL

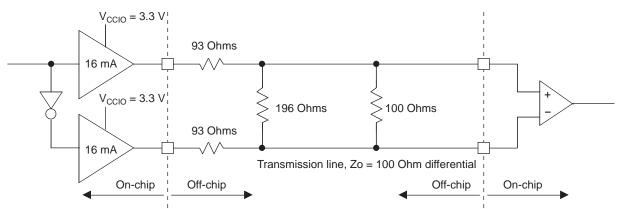


Table 3-3. LVPECL DC Conditions¹

Symbol	Description	Nominal	Units
Z _{OUT}	Output impedance	20	Ohms
R _S	Driver series resistor	93	Ohms
R _P	Driver parallel resistor	196	Ohms
R _T	Receiver termination	100	Ohms
V _{OH}	Output high voltage	2.05	V
V _{OL}	Output low voltage	1.25	V
V _{OD}	Output differential voltage	0.80	V
V _{CM}	Output common mode voltage	1.65	V
Z _{BACK}	Back impedance	100.5	Ohms
DC	DC output current	12.11	mA

Over Recommended Operating Conditions

1. For input buffer, see LVDS table.

For further information on LVPECL, BLVDS and other differential interfaces please see details of additional technical documentation at the end of the data sheet.



MachXO2 External Switching Characteristics – HC/HE Devices^{1, 2, 3, 4, 5, 6, 7}

			-	6	-	5	-4			
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units	
Clocks										
Primary Clo	cks									
f _{MAX_PRI} ⁸	Frequency for Primary Clock Tree	All MachXO2 devices	_	388	_	323	_	269	MHz	
t _{W_PRI}	Clock Pulse Width for Primary Clock	All MachXO2 devices	0.5	_	0.6	_	0.7	_	ns	
		MachXO2-256HC-HE		912		939	—	975	ps	
		MachXO2-640HC-HE		844		871	—	908	ps	
	Primary Clock Skew Within a	MachXO2-1200HC-HE		868		902	—	951	ps	
t _{SKEW_PRI}	Device	MachXO2-2000HC-HE		867		897	—	941	ps	
		MachXO2-4000HC-HE	_	865		892	—	931	ps	
		MachXO2-7000HC-HE	_	902		942	—	989	ps	
Edge Clock									1	
f _{MAX_EDGE} ⁸	Frequency for Edge Clock	MachXO2-1200 and larger devices	_	400	_	333	_	278	MHz	
Pin-LUT-Pin	Propagation Delay	I			1					
t _{PD}	Best case propagation delay through one LUT-4	All MachXO2 devices	_	6.72	_	6.96	_	7.24	ns	
General I/O	Pin Parameters (Using Primary	y Clock without PLL)			1					
		MachXO2-256HC-HE		7.13		7.30		7.57	ns	
		MachXO2-640HC-HE		7.15		7.30	—	7.57	ns	
	Clock to Output – PIO Output	MachXO2-1200HC-HE		7.44		7.64		7.94	ns	
t _{co}	Register	MachXO2-2000HC-HE		7.46		7.66		7.96	ns	
		MachXO2-4000HC-HE		7.51		7.71	—	8.01	ns	
		MachXO2-7000HC-HE		7.54		7.75		8.06	ns	
		MachXO2-256HC-HE	-0.06		-0.06		-0.06	_	ns	
		MachXO2-640HC-HE	-0.06		-0.06	_	-0.06	_	ns	
	Clock to Data Setup – PIO	MachXO2-1200HC-HE	-0.17		-0.17	_	-0.17	_	ns	
t _{SU}	Input Register	MachXO2-2000HC-HE	-0.20		-0.20	_	-0.20	_	ns	
		MachXO2-4000HC-HE	-0.23	_	-0.23	_	-0.23	_	ns	
		MachXO2-7000HC-HE	-0.23	_	-0.23	_	-0.23	_	ns	
		MachXO2-256HC-HE	1.75	—	1.95	—	2.16	—	ns	
		MachXO2-640HC-HE	1.75	_	1.95	_	2.16	_	ns	
	Clock to Data Hold – PIO Input	MachXO2-1200HC-HE	1.88	_	2.12	_	2.36	_	ns	
t _H	Register	MachXO2-2000HC-HE	1.89	_	2.13	_	2.37	_	ns	
		MachXO2-4000HC-HE	1.94		2.18		2.43	_	ns	
		MachXO2-7000HC-HE	1.98	_	2.23	_	2.49	_	ns	

Over Recommended Operating Conditions



			-	-6 –		-5	-	-4	
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units
Generic DDF	R4 Inputs with Clock and Data A	Aligned at Pin Using PC	LK Pin f	or Clock	Input –	GDDRX	4_RX.E	CLK.Ali	gned ^{9, 12}
t _{DVA}	Input Data Valid After ECLK			0.290	_	0.320		0.345	UI
t _{DVE}	Input Data Hold After ECLK	MachXO2-640U,	0.739	—	0.699		0.703	—	UI
f _{DATA}	DDRX4 Serial Input Data Speed	MachXO2-1200/U and larger devices,	_	756	_	630	_	524	Mbps
f _{DDRX4}	DDRX4 ECLK Frequency	bottom side only.11		378		315		262	MHz
f _{SCLK}	SCLK Frequency			95	—	79	—	66	MHz
	4 Inputs with Clock and Data C	entered at Pin Using PC	LK Pin fo	or Clock	Input –	GDDRX4	4_RX.EC	LK.Cen	tered ^{9, 12}
t _{SU}	Input Data Setup Before ECLK		0.233	—	0.219	—	0.198	—	ns
t _{HO}	Input Data Hold After ECLK	MachXO2-640U,	0.287	—	0.287		0.344	—	ns
f _{DATA}	DDRX4 Serial Input Data Speed	MachXO2-1200/U and larger devices,	_	756	_	630	_	524	Mbps
f _{DDRX4}	DDRX4 ECLK Frequency	bottom side only.11		378	—	315		262	MHz
f _{SCLK}	SCLK Frequency			95	—	79	_	66	MHz
7:1 LVDS In	puts (GDDR71_RX.ECLK.7:1) ^{9,}	12							
t _{DVA}	Input Data Valid After ECLK			0.290		0.320		0.345	UI
t _{DVE}	Input Data Hold After ECLK		0.739	—	0.699		0.703	—	UI
f _{DATA}	DDR71 Serial Input Data Speed	MachXO2-640U, MachXO2-1200/U and	_	756	_	630	_	524	Mbps
f _{DDR71}	DDR71 ECLK Frequency	larger devices, bottom side only.11		378		315		262	MHz
f _{CLKIN}	7:1 Input Clock Frequency (SCLK) (minimum limited by PLL)		_	108	_	90	_	75	MHz
Generic DDF	R Outputs with Clock and Data	Aligned at Pin Using PC	LK Pin f	for Clock	k Input –	GDDR	(1_TX.S	CLK.Ali	gned ^{9, 12}
t _{DIA}	Output Data Invalid After CLK Output			0.520	_	0.550	_	0.580	ns
t _{DIB}	Output Data Invalid Before CLK Output	All MachXO2 devices, all sides.	_	0.520	_	0.550	_	0.580	ns
f _{DATA}	DDRX1 Output Data Speed			300		250		208	Mbps
f _{DDRX1}	DDRX1 SCLK frequency	-		150	—	125		104	MHz
	Outputs with Clock and Data C	entered at Pin Using PC	LK Pin f	or Clock	Input –	GDDRX	1_TX.SC	LK.Cen	tered ^{9, 12}
t _{DVB}	Output Data Valid Before CLK Output		1.210	_	1.510	_	1.870	_	ns
t _{DVA}	Output Data Valid After CLK Output	All MachXO2 devices,	1.210	_	1.510	_	1.870	_	ns
f _{DATA}	DDRX1 Output Data Speed	all sides.		300	—	250	_	208	Mbps
f _{DDRX1}	DDRX1 SCLK Frequency (minimum limited by PLL)	-		150	_	125	_	104	MHz
Generic DDF	X2 Outputs with Clock and Data	a Aligned at Pin Using P	CLK Pin	for Cloc	k Input	- GDDR	X2_TX.E	CLK.Ali	gned ^{9, 12}
t _{DIA}	Output Data Invalid After CLK Output		_	0.200	_	0.215	_	0.230	ns
t _{DIB}	Output Data Invalid Before CLK Output	MachXO2-640U, MachXO2-1200/U and	_	0.200	_	0.215	_	0.230	ns
f _{DATA}	DDRX2 Serial Output Data Speed	larger devices, top side only.	_	664	_	554	_	462	Mbps
f _{DDRX2}	DDRX2 ECLK frequency	1		332	—	277	_	231	MHz
f _{SCLK}	SCLK Frequency	1	—	166	—	139	_	116	MHz



MachXO2 External Switching Characteristics – ZE Devices^{1, 2, 3, 4, 5, 6, 7}

			-	-3	-	2	-1			
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units	
Clocks										
Primary Cloo	cks									
f _{MAX_PRI} ⁸	Frequency for Primary Clock Tree	All MachXO2 devices	_	150	_	125	—	104	MHz	
t _{W_PRI}	Clock Pulse Width for Primary Clock	All MachXO2 devices	1.00	_	1.20	_	1.40	_	ns	
		MachXO2-256ZE	—	1250		1272	—	1296	ps	
		MachXO2-640ZE		1161		1183	—	1206	ps	
	Primary Clock Skew Within a	MachXO2-1200ZE		1213		1267	—	1322	ps	
^t SKEW_PRI	Device	MachXO2-2000ZE		1204		1250	—	1296	ps	
		MachXO2-4000ZE		1195		1233	—	1269	ps	
		MachXO2-7000ZE		1243		1268	—	1296	ps	
Edge Clock										
f _{MAX_EDGE⁸}	Frequency for Edge Clock	MachXO2-1200 and larger devices	_	210	_	175	_	146	MHz	
Pin-LUT-Pin	Propagation Delay			1	1				1	
t _{PD}	Best case propagation delay through one LUT-4	All MachXO2 devices	_	9.35	_	9.78	_	10.21	ns	
General I/O I	Pin Parameters (Using Primary	Clock without PLL)	1			1		1		
		MachXO2-256ZE		10.46	—	10.86	—	11.25	ns	
		MachXO2-640ZE		10.52		10.92	—	11.32	ns	
	Clock to Output – PIO Output Register	MachXO2-1200ZE		11.24		11.68	—	12.12	ns	
t _{CO}		MachXO2-2000ZE		11.27		11.71	—	12.16	ns	
		MachXO2-4000ZE		11.28		11.78	—	12.28	ns	
		MachXO2-7000ZE	—	11.22		11.76	—	12.30	ns	
		MachXO2-256ZE	-0.21		-0.21	—	-0.21	—	ns	
		MachXO2-640ZE	-0.22	—	-0.22	—	-0.22	—	ns	
	Clock to Data Setup – PIO	MachXO2-1200ZE	-0.25	—	-0.25	—	-0.25	—	ns	
t _{SU}	Input Register	MachXO2-2000ZE	-0.27	—	-0.27	—	-0.27	—	ns	
		MachXO2-4000ZE	-0.31	—	-0.31		-0.31		ns	
		MachXO2-7000ZE	-0.33	—	-0.33		-0.33		ns	
		MachXO2-256ZE	3.96		4.25	_	4.65	_	ns	
		MachXO2-640ZE	4.01		4.31	—	4.71	—	ns	
+	Clock to Data Hold – PIO Input	MachXO2-1200ZE	3.95		4.29	_	4.73	_	ns	
t _H	Register	MachXO2-2000ZE	3.94	—	4.29	—	4.74	—	ns	
		MachXO2-4000ZE	3.96		4.36	—	4.87	—	ns	
		MachXO2-7000ZE	3.93		4.37	—	4.91		ns	
		IVIACHAU2-7000ZE	3.93	—	4.37		4.91			

Over Recommended Operating Conditions



sysCLOCK PLL Timing (Continued)

Over Recommended Operating Conditions

Parameter	Descriptions	Conditions	Min.	Max.	Units
t _{ROTATE_WD}	PHASESTEP Pulse Width		4	_	VCO Cycles

1. Period jitter sample is taken over 10,000 samples of the primary PLL output with a clean reference clock. Cycle-to-cycle jitter is taken over 1000 cycles. Phase jitter is taken over 2000 cycles. All values per JESD65B.

2. Output clock is valid after t_{LOCK} for PLL reset and dynamic delay adjustment.

3. Using LVDS output buffers.

4. CLKOS as compared to CLKOP output for one phase step at the maximum VCO frequency. See TN1199, MachXO2 sysCLOCK PLL Design and Usage Guide for more details.

5. At minimum f_{PFD} As the f_{PFD} increases the time will decrease to approximately 60% the value listed.

6. Maximum allowed jitter on an input clock. PLL unlock may occur if the input jitter exceeds this specification. Jitter on the input clock may be transferred to the output clocks, resulting in jitter measurements outside the output specifications listed in this table.

7. Edge Duty Trim Accuracy is a percentage of the setting value. Settings available are 70 ps, 140 ps, and 280 ps in addition to the default value of none.

8. Jitter values measured with the internal oscillator operating. The jitter values will increase with loading of the PLD fabric and in the presence of SSO noise.



Flash Download Time^{1, 2}

Symbol	Symbol Parameter Device		Тур.	Units
		LCMXO2-256	0.6	ms
		LCMXO2-640	1.0	ms
		LCMXO2-640U	1.9	ms
		LCMXO2-1200	1.9	ms
t _{REFRESH}	POR to Device I/O Active	LCMXO2-1200U	1.4	ms
		LCMXO2-2000	1.4	ms
		LCMXO2-2000U	2.4	ms
		LCMXO2-4000	2.4	ms
		LCMXO2-7000	3.8	ms

1. Assumes sysMEM EBR initialized to an all zero pattern if they are used.

2. The Flash download time is measured starting from the maximum voltage of POR trip point.

JTAG Port Timing Specifications

Symbol	Parameter	Min.	Max.	Units
f _{MAX}	TCK clock frequency		25	MHz
t _{BTCPH}	TCK [BSCAN] clock pulse width high	20	—	ns
t _{BTCPL}	TCK [BSCAN] clock pulse width low	20	—	ns
t _{BTS}	TCK [BSCAN] setup time	10	—	ns
t _{BTH}	TCK [BSCAN] hold time	8	—	ns
t _{BTCO}	TAP controller falling edge of clock to valid output	_	10	ns
t _{BTCODIS}	TAP controller falling edge of clock to valid disable	_	10	ns
t _{BTCOEN}	TAP controller falling edge of clock to valid enable	_	10	ns
t _{BTCRS}	BSCAN test capture register setup time	8	—	ns
t _{BTCRH}	BSCAN test capture register hold time	20	—	ns
t _{BUTCO}	BSCAN test update register, falling edge of clock to valid output	_	25	ns
t _{BTUODIS}	BSCAN test update register, falling edge of clock to valid disable	_	25	ns
t _{BTUPOEN}	BSCAN test update register, falling edge of clock to valid enable		25	ns



	MachXO2-2000					MachXO2-2000U	
	49 WLCSP	100 TQFP	132 csBGA	144 TQFP	256 caBGA	256 ftBGA	484 ftBGA
General Purpose I/O per Bank	•				•		
Bank 0	19	18	25	27	50	50	70
Bank 1	0	21	26	28	52	52	68
Bank 2	13	20	28	28	52	52	72
Bank 3	0	6	7	8	16	16	24
Bank 4	0	6	8	10	16	16	16
Bank 5	6	8	10	10	20	20	28
Total General Purpose Single-Ended I/O	38	79	104	111	206	206	278
Differential I/O per Bank							
Bank 0	7	9	13	14	25	25	35
Bank 1	0	10	13	14	26	26	34
Bank 2	6	10	14	14	26	26	36
Bank 3	0	3	3	4	8	8	12
Bank 4	0	3	4	5	8	8	8
Bank 5	3	4	5	5	10	10	14
Total General Purpose Differential I/O	16	39	52	56	103	103	139
Dual Function I/O	24	31	33	33	33	33	37
High-speed Differential I/O		-					_
Bank 0	5	4	8	9	14	14	18
Gearboxes	-		-	_			-
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	5	4	8	9	14	14	18
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	6	10	14	14	14	14	18
DQS Groups							
Bank 1	0	1	2	2	2	2	2
VCCIO Pins							
Bank 0	2	2	3	3	4	4	10
Bank 1	0	2	3	3	4	4	10
Bank 2	1	2	3	3	4	4	10
Bank 3	0	1	1	1	1	1	3
Bank 4	0	1	1	1	2	2	4
Bank 5	1	1	1	1	1	1	3
			•		1	r	T
VCC	2	2	4	4	8	8	12
GND	4	8	10	12	24	24	48
NC	0	1	1	4	1	1	105
Reserved for Configuration	1	1	1	1	v	1	1
Total Count of Bonded Pins	39	100	132	144	256	256	484



MachXO2 Family Data Sheet Revision History

March 2017

Data Sheet DS1035

Date	Version	Section	Change Summary
March 2017 3.3	DC and Switching Characteristics	Updated the Absolute Maximum Ratings section. Added standards.	
			Updated the sysIO Recommended Operating Conditions section. Added standards.
			Updated the sysIO Single-Ended DC Electrical Characteristics sec- tion. Added standards.
			Updated the MachXO2 External Switching Characteristics – HC/HE Devices section. Under 7:1 LVDS Outputs – GDDR71_TX.ECLK.7:1, the D_{VB} and the D_{VA} parameters were changed to D_{IB} and D_{IA} . The parameter descriptions were also modified.
			Updated the MachXO2 External Switching Characteristics – ZE Devices section. Under 7:1 LVDS Outputs – GDDR71_TX.ECLK.7:1, the D_{VB} and the D_{VA} parameters were changed to D_{IB} and D_{IA} . The parameter descriptions were also modified.
			Updated the sysCONFIG Port Timing Specifications section. Corrected the t_{INITL} units from ns to μ s.
		Pinout Information	Updated the Signal Descriptions section. Revised the descriptions of the PROGRAMN, INITN, and DONE signals.
			Updated the Pinout Information Summary section. Added footnote to MachXO2-1200 32 QFN.
		Ordering Information	Updated the MachXO2 Part Number Description section. Corrected the MG184, BG256, FTG256 package information. Added "(0.8 mm Pitch)" to BG332.
			Updated the Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. — Updated LCMXO2-1200ZE-1UWG25ITR50 footnote. — Corrected footnote numbering typo. — Added the LCMXO2-2000ZE-1UWG49ITR50 and LCMXO2- 2000ZE-1UWG49ITR1K part numbers. Updated/added footnote/s.

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Date	Version	Section	Change Summary
December 2014 2.9		Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Removed XO2-4000U data. — Removed 400-ball ftBGA. — Removed 25-ball WLCSP value for XO2-2000U.
		DC and Switching Characteristics	Updated the Recommended Operating Conditions section. Adjusted Max. values for V_{CC} and V_{CCIO}
			Updated the sysIO Recommended Operating Conditions section. Adjusted Max. values for LVCMOS 3.3, LVTTL, PCI, LVDS33 and LVPECL.
		Pinout Information	Updated the Pinout Information Summary section. Removed MachXO2-4000U.
		Ordering Information	Updated the MachXO2 Part Number Description section. Removed BG400 package.
			Updated the High-Performance Commercial Grade Devices with Volt- age Regulator, Halogen Free (RoHS) Packaging section. Removed LCMXO2-4000UHC part numbers.
			Updated the High-Performance Industrial Grade Devices with Voltage Regulator, Halogen Free (RoHS) Packaging section. Removed LCMXO2-4000UHC part numbers.
November 2014 2.8	2.8	Introduction	Updated the Features section. — Revised I/Os under Flexible Logic Architecture. — Revised standby power under Ultra Low Power Devices. — Revise input frequency range under Flexible On-Chip Clocking.
		Updated Table 1-1, MachXO2 Family Selection Guide. — Added XO2-4000U data. — Removed HE and ZE device options for XO2-4000. — Added 400-ball ftBGA.	
		Pinout Information	Updated the Pinout Information Summary section. Added MachXO2-4000U caBGA400 and MachXO2-7000 caBGA400.
		Ordering Information	Updated the MachXO2 Part Number Description section. Added BG400 package.
			Updated the Ordering Information section. Added MachXO2-4000U caBGA400 and MachXO2-7000 caBGA400 part numbers.
October 2014	2.7	Ordering Information	Updated the Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Fixed typo in LCMXO2-2000ZE- 1UWG49ITR part number package.
		Architecture	Updated the Supported Standards section. Added MIPI information to Table 2-12. Supported Input Standards and Table 2-13. Supported Output Standards.
		DC and Switching Characteristics	Updated the BLVDS section. Changed output impedance nominal values in Table 3-2, BLVDS DC Condition.
			Updated the LVPECL section. Changed output impedance nominal value in Table 3-3, LVPECL DC Condition.
		Updated the sysCONFIG Port Timing Specifications section. Updated INITN low time values.	
July 2014	2.6	DC and Switching Characteristics	Updated sysIO Single-Ended DC Electrical Characteristics ^{1, 2} section. Updated footnote 4.
			Updated Register-to-Register Performance section. Updated foot- note.
		Ordering Information	Updated UW49 package to UWG49 in MachXO2 Part Number Description.
			Updated LCMXO2-2000ZE-1UWG49CTR package in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging.



Image: space with the second secon	Date	Version	Section	Change Summary
Guide table. Architecture Added information to Standby Mode and Power Saving Options section. Pinout Information Added the XO2-2000 49 WLCSP in the Pinout Information Summary table. Ordering Information Added the XO2-2000 2E in the Pinout Information Summary table. Ordering Information Added the XO2-2000ZE-1UWG49CTR in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging section. Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. December 2013 02.3 Architecture Updated Information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section. DC and Switching Updated footnote 4 in sysIO Single-Ended DC Electrical Characteristics table; Updated V _{IL} Max. (V) data for LVCMOS 25 and LVCMOS 28. Updated V _{OS} test condition in sysIO Differential Electrical Characteristics - LVDS table. Updated Supported Input Standards table. DC and Switching Updated Power-On-Reset Voltage Levels table. Updated Supported Input Standards table. June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration. June 2013 02.1 Architecture Architec	May 2014	2.5	Architecture	Updated TransFR description for PLL use during background Flash
Image: section of the sectio	February 2014 02.4		Introduction	
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Added and LCMXO2-2000ZE-1UWG49CTR in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging section. Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. December 2013 02.3 Architecture Updated information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section. DC and Switching Characteristics Updated Static Supply Current – ZE Devices table. Updated footnote 4 in sysIO Single-Ended DC Electrical Characteris tics table; Updated V _{IL} Max. (V) data for LVCMOS 25 and LVCMOS 28. Updated Vos test condition in sysIO Differential Electrical Characteri- istics - LVDS table. September 2013 02.2 Oz and Switching Characteristics Removed I ² C Clock-Stretching feature per PCN #10A-13. Removed information on PDPR memory in RAM Mode section. Updated Supported Input Standards table. June 2013 02.1 Architecture Architecture Overview – Added information on the state of the regis- ter on power up and after configuration. sysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOC KPLL Timing table. Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.			Pinout Information	Added the XO2-2000 49 WLCSP in the Pinout Information Summary table.
Image: bit is a series of the serie			Ordering Information	Added UW49 package in MachXO2 Part Number Description.
Industrial Grade Devices, Halogen Free (RoHS) Packaging section. December 2013 02.3 Architecture Updated information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section. DC and Switching Characteristics Updated Static Supply Current – ZE Devices table. Updated footnote 4 in sysIO Single-Ended DC Electrical Characteris tics table; Updated V _{IL} Max. (V) data for LVCMOS 25 and LVCMOS 28. September 2013 02.2 Architecture Removed I ² C Clock-Stretching feature per PCN #10A-13. Removed I ² C Clock-Stretching feature per PCN #10A-13. Removed information on PDPR memory in RAM Mode section. Updated Supported Input Standards table. Updated Power-On-Reset Voltage Levels table. June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration. SysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table. DC and Switching Characteristics Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – ED Povices and the MachXO2 External Switching Characteristics – ZE Devices tables.				Commercial Grade Devices, Halogen Free (RoHS) Packaging sec-
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September 2013 02.2 Architecture Removed I ² C Clock-Stretching feature per PCN #10A-13. Removed information on PDPR memory in RAM Mode section. Updated Supported Input Standards table. DC and Switching Characteristics Updated Power-On-Reset Voltage Levels table. June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration. SysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table. DC and Switching Characteristics DC and Switching Characteristics Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.				
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Cross reference to sysCLOCK PLL Timing table. DC and Switching Characteristics Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.	June 2013	02.1	Architecture	
Characteristics Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.				
Power-On-Reset Voltage Levels table – Added symbols.				Switching Characteristics - HC/HE Devices and the MachXO2 Exter-
				Power-On-Reset Voltage Levels table – Added symbols.



Date	Version	Section	Change Summary	
February 2012	01.7	All	Updated document with new corporate logo.	
	01.6	—	Data sheet status changed from preliminary to final.	
	Introduction	MachXO2 Family Selection Guide table – Removed references to 49-ball WLCSP.		
		DC and Switching Characteristics	Updated Flash Download Time table.	
			Modified Storage Temperature in the Absolute Maximum Ratings section.	
			Updated I _{DK} max in Hot Socket Specifications table.	
			Modified Static Supply Current tables for ZE and HC/HE devices.	
			Updated Power Supply Ramp Rates table.	
			Updated Programming and Erase Supply Current tables.	
			Updated data in the External Switching Characteristics table.	
			Corrected Absolute Maximum Ratings for Dedicated Input Voltage Applied for LCMXO2 HC.	
			DC Electrical Characteristics table – Minor corrections to conditions for $\mathbf{I}_{IL}, \mathbf{I}_{IH.}$	
		Pinout Information	Removed references to 49-ball WLCSP.	
			Signal Descriptions table – Updated description for GND, VCC, and VCCIOx.	
			Updated Pin Information Summary table – Number of VCCIOs, GNDs, VCCs, and Total Count of Bonded Pins for MachXO2-256, 640, and 640U and Dual Function I/O for MachXO2-4000 332caBGA.	
	Ordering Information	Removed references to 49-ball WLCSP		
August 2011	01.5	DC and Switching Characteristics	Updated ESD information.	
		Ordering Information	Updated footnote for ordering WLCSP devices.	
	01.4	Architecture	Updated information in Clock/Control Distribution Network and sys- CLOCK Phase Locked Loops (PLLs).	
		DC and Switching Characteristics	Updated ${\rm I}_{\rm IL}$ and ${\rm I}_{\rm IH}$ conditions in the DC Electrical Characteristics table.	
		Pinout Information	Included number of 7:1 and 8:1 gearboxes (input and output) in the pin information summary tables.	
		Updated Pin Information Summary table: Dual Function I/O, DQS Groups Bank 1, Total General Purpose Single-Ended I/O, Differential I/O Per Bank, Total Count of Bonded Pins, Gearboxes.		
			Added column of data for MachXO2-2000 49 WLCSP.	
	Ordering Information	Updated R1 Device Specifications text section with information on migration from MachXO2-1200-R1 to Standard (non-R1) devices.		
			Corrected Supply Voltage typo for part numbers: LCMX02-2000UHE- 4FG484I, LCMX02-2000UHE-5FG484I, LCMX02-2000UHE- 6FG484I.	
			Added footnote for WLCSP package parts.	
		Supplemental Information	Removed reference to Stand-alone Power Calculator for MachXO2 Devices. Added reference to AN8086, Designing for Migration from MachXO2-1200-R1 to Standard (non-R1) Devices.	